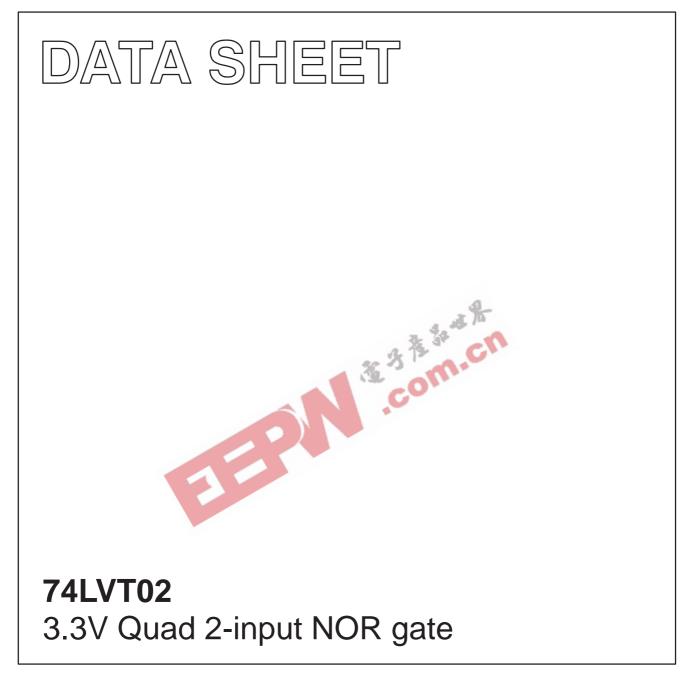
INTEGRATED CIRCUITS



Product specification

1996 Aug 15

IC24 Data Handbook



74LVT02

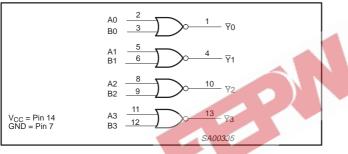
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS T _{amb} = 25°C; GND = 0V	TYPICAL	UNIT
tPLH tPHL	Propagation delay An or Bn to Ƴn	C _L = 50pF; V _{CC} = 3.3V	2.8 2.6	ns
C _{IN}	Input capacitance	$V_{I} = 0V \text{ or } 3.0V$	3	pF
I _{CCL}	Total supply current	Outputs Low; $V_{CC} = 3.6V$	1	mA

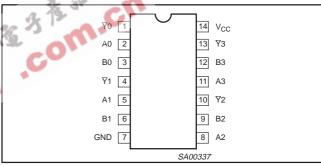
ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
14-Pin Plastic SO	-40°C to +85°C	74LVT02 D	74LVT02 D	SOT108-1
14-Pin Plastic SSOP	-40°C to +85°C	74LVT02 DB	74LVT02 DB	SOT337-1
14-Pin Plastic TSSOP	-40°C to +85°C	74LVT02 PW	74LVT02PW DH	SOT402-1

LOGIC SYMBOL

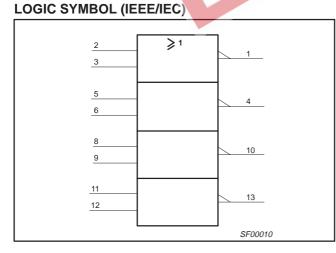


PIN CONFIGURATION



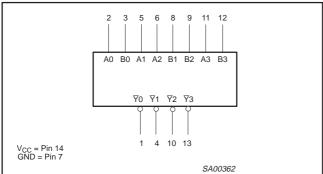
PIN DESCRIPTION

	PIN NUMBER	SYMBOL	NAME AND FUNCTION
	2, 3, 5, 6, 8, 9, 11, 12	An-Bn	Data inputs
ĺ	1, 4, 10, 13	Ϋ́n	Data outputs
	7	GND	Ground (0V)
ĺ	14	V _{CC}	Positive supply voltage



74LVT02

LOGIC DIAGRAM



FUNCTION TABLE

INP	JTS	OUTPUT
Dna	Dnb	Qn
L	L	Н
L	Н	L
Н	L	L
Н	Н	L

NOTES:

H = High voltage level L = Low voltage level

ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	PARAMETER CONDITIONS		UNIT	
V _{CC}	DC supply voltage	1 15	-0.5 to +4.6	V	
I _{IK}	DC input diode current	rent V ₁ < 0		mA	
VI	DC input voltage ³	372 0	-0.5 to +7.0	V	
I _{OK}	DC output diode current	V _O < 0	-50	mA	
V _{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V	
	DC output current	Output in High state	-32	mA	
I _{OUT} DC outp		Output in Low state	64		
T _{stg}	Storage temperature range		-65 to 150	°C	

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction 2. temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.

3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER		LIMITS	
STMBOL	FARAWETER	MIN	MAX	UNIT
V _{CC}	DC supply voltage	2.7	3.6	V
VI	Input voltage	0	5.5	V
V _{IH}	High-level input voltage	2.0		V
V _{IL}	Low-level Input voltage		0.8	V
I _{ОН}	I _{OH} High-level output current		-20	mA
I _{OL}	Low-level output current		32	mA
Δt/Δv	Input transition rise or fall rate; Outputs enabled		10	ns/V
T _{amb}	Operating free-air temperature range		+85	°C

74LVT02

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions Voltages are referenced to GND (ground = 0V)

	PARAMETER TEST CONDITIONS		LIMITS			
SYMBOL		Temp = -40°C to +85°C				
			MIN	TYP ¹	MAX	1
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA			-1.2	V
		$V_{CC} = 2.7$ to 3.6V; $I_{OH} = -100\mu A$	V _{CC} -0.2			
V _{OH}	High-level output voltage	V _{CC} = 2.7V; I _{OH} = -6mA	2.4			V
		V _{CC} = 3.0V; I _{OH} = -20mA	2.0			1
V _{OL} Low-level output voltage		V _{CC} = 2.7V; I _{OL} = 100μA			0.2	
	Low-level output voltage	V _{CC} = 2.7V; I _{OL} = 24mA			0.5	V
		V _{CC} = 3.0V; I _{OL} = 32mA			0.5	1
		$V_{CC} = 0 \text{ or } 3.6V; V_{I} = 5.5V$			10	
1 ₁	Input leakage current	$V_{CC} = 3.6V; V_1 = V_{CC} \text{ or GND}$			±1	μA
I _{OFF}	Output off current	$V_{CC} = 0V; V_1 \text{ or } V_O = 0 \text{ to } 4.5V$			±100	μΑ
I _{CCH}		$V_{CC} = 3.6V$; Outputs High, $V_I = GND$ or V_{CC} , $I_O = 0$			0.02	mA
I _{CCL}	Quiescent supply current	$V_{CC} = 3.6V$; Outputs Low, $V_I = GND$ or V_{CC} , $I_O = 0$		1	2	
ΔI_{CC}	Additional supply current per input pin ²	V_{CC} = 3V to 3.6V; One input at V_{CC}-0.6V, Other inputs at V_{CC} or GND			0.2	μΑ
CI	Input capacitance	$V_{I} = 3V \text{ or } 0$		3		pF

NOTES:

1. All typical values are at $V_{CC} = 3.3$ V and $T_{amb} = 25$ °C. 2. This is the increase in supply current for each input at the specificed voltage level other than V_{CC} or GND.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$, $R_L = 500\Omega$; $T_{amb} = -40^{\circ}C$ to +85°C.

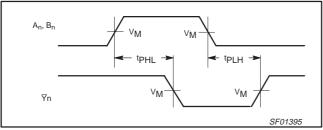
			LIMITS				
SYMBOL	PARAMETER	WAVEFORM	$V_{CC}=3.3V\pm0.3V$			$V_{CC} = 2.7V$	UNIT
			MIN	TYP ¹	MAX	MAX	
t _{PLH} t _{PHL}	Propagation delay An or Bn to Ƴn	1	1.0 1.0	2.8 2.6	4.4 3.6	5.2 3.4	ns

NOTE:

1. All typical values are at V_{CC} = 3.3V and T_{amb} = 25°C.

AC WAVEFORMS

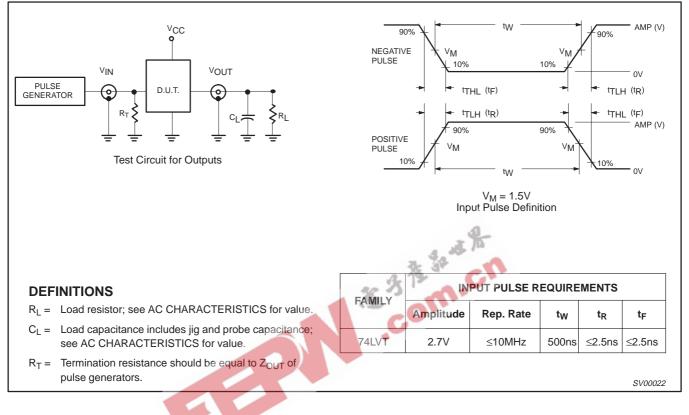
 V_{M} = 1.5V, V_{IN} = GND to 2.7V

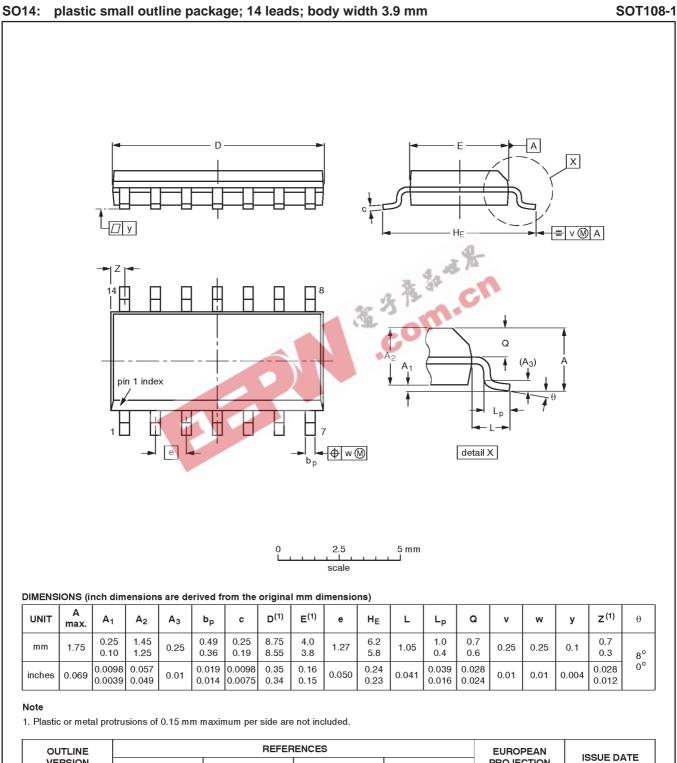


Waveform 1. Propagation delay for inverting outputs

74LVT02

TEST CIRCUIT AND WAVEFORMS





1996 Aug 15

VERSION

SOT108-1

IEC

076E06S

JEDEC

MS-012AB

EIAJ

PROJECTION

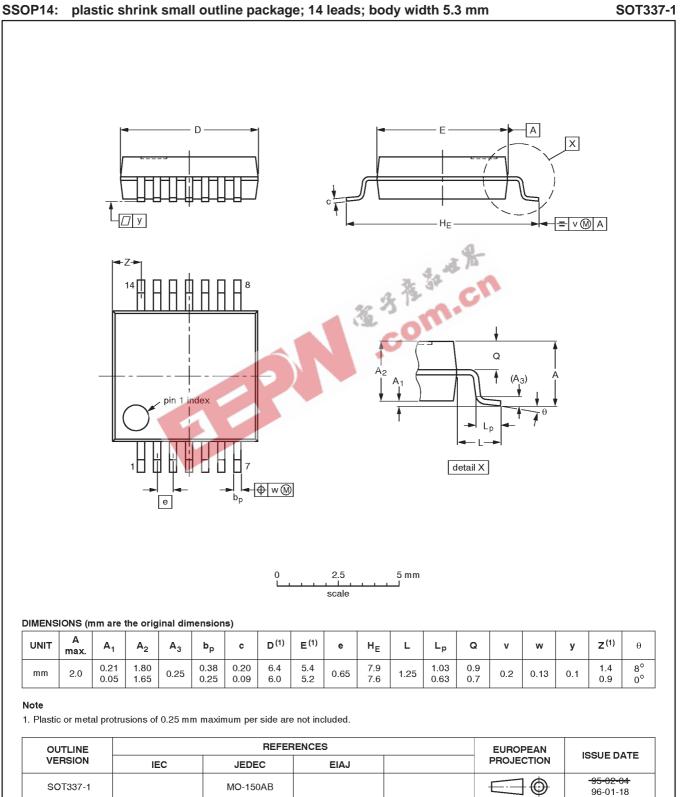
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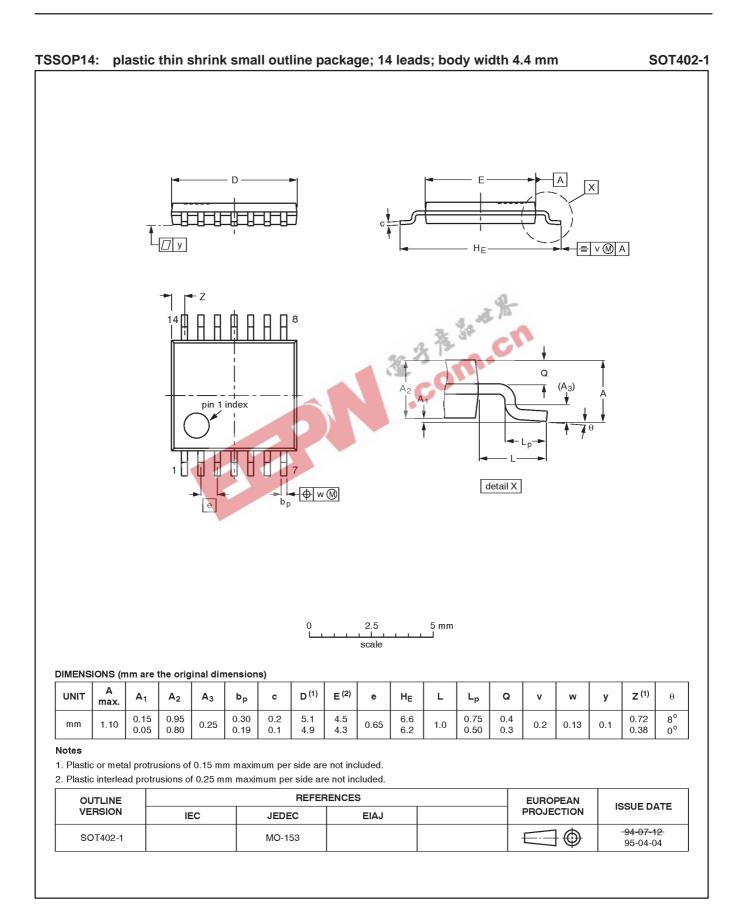
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NOTES



74LVT02



DEFINITIONS				
Data Sheet Identification	Product Status	Definition		
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.		
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.		
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